



CD22101, CD22102

CMOS 4 x 4 x 2 Crosspoint Switch with Control Memory

March 1993

Features

- Low ON Resistance75V Typ. at $V_{DD} = 12V$
- "Built - In" Latched Inputs
- Large Analog Signal Capability $\pm V_{DD}/2$
- Switch Bandwidth 10MHz
- Matched Switch Characteristics $\Delta R_{ON} = 8\Omega$ Typ. at $V_{DD} = 12V$
- High Linearity - 0.25% Distortion (Typ.) at $f = 1kHz$, $V_{IN} = 5V_{p-p}$, $V_{DD} - V_{SS} = 10V$, and $R_L = 1k\Omega$
- Standard CMOS Noise Immunity

Applications

- Telephone Systems
- PBX
- Studio Audio Switching
- Multisystem Bus Interconnect

Ordering Information

PART NUMBER	TEMPERATURE RANGE	PACKAGE
CD22101E	-40°C to +85°C	24 Lead Plastic DIP
CD22101F	-55°C to +125°C	24 Lead Frit Seal Ceramic DIP
CD22102E	-40°C to +85°C	24 Lead Plastic DIP
CD22102F	-55°C to +125°C	24 Lead Frit Seal Ceramic DIP

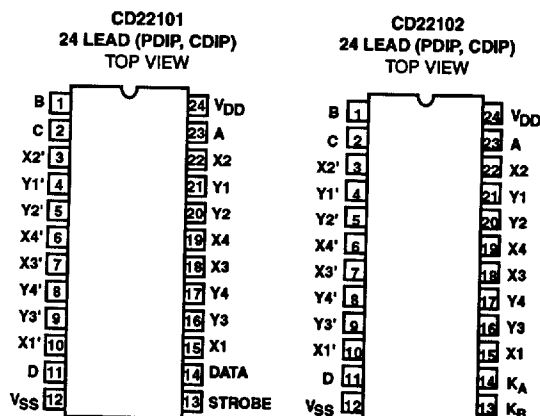
Description

CD22101 and CD22102 crosspoint switches consist of 4 x 4 x 2 arrays of crosspoints (transmission gates) with a 4-line to 16-line decoder and 16 latch circuits. Any one of the sixteen crosspoint pairs can be selected by applying the appropriate four-line address, corresponding crosspoints in each array are turned on and off simultaneously. Any number of crosspoints can be turned on simultaneously.

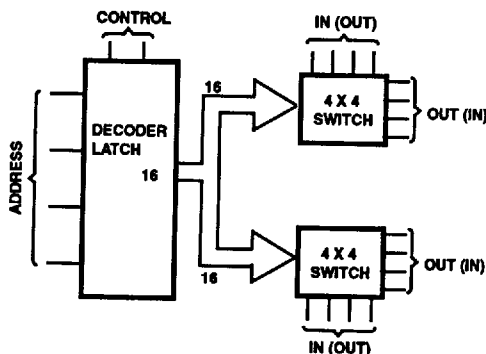
In the CD22101, the selected crosspoint pair can be turned on or off by applying a logical ONE or ZERO, respectively, to the data input, and applying a ONE to the strobe input. When the device is "powered up", the states of the 16 switches are indeterminate. Therefore, all switches must be turned off by putting the strobe high, data-in low, and then addressing all switches in succession.

The selected pair of crosspoints in the CD22102 is turned on by applying a logical ONE to the K_A (set) input while a logical ZERO is on the K_B input, and turned off by applying a logical ONE to the K_B (reset) input while a logical ZERO is on the K_A input. In this respect, the control latches of the CD22102 are similar to SET/RESET flip-flops. They differ, however, in that the simultaneous application of ONE's to the K_A and K_B inputs turns off (resets) all crosspoints. All crosspoints in both devices must be turned off as V_{DD} is applied.

Pinouts



Functional Diagram



Specifications CD22101, CD22102

Absolute Maximum Ratings

Supply Voltage (V_{DD})(Voltages referenced to V_{SS} Terminal).....-0.5 to +20VInput Voltage (All Inputs) -0.5 to $V_{DD} + 0.5V$ Input Current (Any One Input) (Note 1) $\pm 10mA$

Power Dissipation

For $T_A = -40^\circ C$ to $+60^\circ C$ (Package Type E) 500mWFor $T_A = +60^\circ C$ to $+85^\circ C$ (Package Type E) Derate Linearly 12mW/ $^\circ C$ to 200mWFor $T_A = -55^\circ C$ to $+100^\circ C$ (Package Type D, F) 500mWFor $T_A = +100^\circ C$ to $+125^\circ C$ (Package Type D, F) Derate Linearly 12mW/ $^\circ C$ to 200mW

Device Dissipation per Output Transistor

For $T_A =$ Full Package Temperature Range (All Types) 100mWJunction Temperature $+175^\circ C$ Junction Temperature (Plastic Package) $+150^\circ C$ Lead Temperature (Soldering 10 Sec.) $+300^\circ C$

Recommended Operating Conditions

Operating Temperature Range

Package Type D, F, H $-55^\circ C \leq T_A \leq +125^\circ C$ Package Type E $-40^\circ C \leq T_A \leq +85^\circ C$ Storage Temperature Range $-65^\circ C \leq T_A \leq +150^\circ C$

Supply Voltage Range

For $T_A =$ Full Package Temperature Range $+3V$ to $+18V$

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Static Electrical Specifications

Values at $-55^\circ C$, $+25^\circ C$, $+125^\circ C$ Apply to D, F, H PackagesValues at $-40^\circ C$, $+25^\circ C$, $+85^\circ C$ Apply to E Package

PARAMETERS	SYMBOL	TEST CONDITIONS		LIMITS AT INDICATED TEMPERATURES								UNITS	
				FIGURE	V _{DD} (V)	-55°C	-40°C	+85°C	+125°C	+25°C			
										MIN	TYP		MAX
CROSSPOINTS													
Quiescent Device Current	I _{DD} Max.		1	5	5	5	150	150	-	0.04	5	μA	
			1	10	10	10	300	300	-	0.04	10	μA	
			1	15	20	20	600	600	-	0.04	20	μA	
			1	20	100	100	3000	3000	-	0.08	100	μA	
On Resistance	R _{ON} Max.	Any Switch V _{IS} = 0 to V _{DD}	14	5	475	500	725	800	-	225	600	Ω	
			15	10	135	145	205	230	-	85	180	Ω	
			-	12	100	110	155	175	-	75	135	Ω	
			16	15	70	75	110	125	-	65	95	Ω	
Δ _{ON} Resistance	ΔR _{ON}	Between any two switches	5	-	-	-	-	-	-	25	-	Ω	
			10	-	-	-	-	-	-	10	-	Ω	
			12	-	-	-	-	-	-	8	-	Ω	
			15	-	-	-	-	-	-	5	-	Ω	
OFF Leakage Current	I _L Max.	All switches OFF, V _{IS} = 18V	4	18	±1000			-	±1	±100 (Note 2)	nA		
CONTROLS													
Input Low Voltage	V _{IL} Max.	OFF switch I _L < 0.2μA	5	1.5			-	-	1.5	V			
			10	3			-	-	3	V			
			15	4			-	-	4	V			
Input High Voltage	V _{IH} Min.	ON switch see R _{ON} characteristic	5	3.5			3.5	-	-	V			
			10	7			7	-	-	V			
			15	11			11	-	-	V			
Input Current	I _{IN} Max.	Any control V _{IN} = 0, 18V	2	18	±0.1	±0.1	±1	±1	-	±10 ⁻⁶	±0.1	μA	

NOTE:

- Maximum current through transmission gates (switches) = 25mA.
- Determined by minimum feasible leakage measurement for automatic testing.

Specifications CD22101, CD22102

Dynamic Electrical Specifications $T_A = +25^\circ\text{C}$

PARAMETERS	SYMBOL	FIGURE	TEST CONDITIONS				LIMITS			UNITS	
			f_{is} (kHz)	R_L (k Ω)	V_{is} (V) (Note 3)	V_{DD} (V)	MIN	TYP	MAX		
CROSSPOINTS											
Propagation Delay Time, (Switch ON) Signal Input to Output	t_{PHL}, t_{PLH}	5			5	5	-	30	60	ns	
			-	10	10	10	-	15	30	ns	
					15	15	-	10	20	ns	
			$C_L = 50\text{pF}; t_R, t_F = 20\text{ns}$								
Frequency Response (Any switch ON)	f_{3dB}	19	1	1	5	10	-	40	-	MHz	
			$\text{Sine wave input, } 20 \log \frac{V_{OS}}{V_{IS}} = -3\text{dB}$								
Sine Wave Response (Distortion)	THD	-	1	1	2.5	5	-	1	-	%	
			1	1	5	10	-	0.25	-	%	
			1	1	7.5	15	-	0.15	-	%	
Feedthrough (All switches OFF)	F_{DT}	13	1.6	0.6	2 (Note 4)	10	-	-96	-	dB	
			Sine wave input								
Frequency for Signal Crosstalk Attenuation of 40dB	F_{CT}	12	-	0.6	1 (Note 4)	10	-	2.5	-	MHz	
			Sine wave input				-	0.1	-	kHz	
Capacitance:											
X_N to Ground	C_{IS}			-	-	-	-	25	-	pF	
Y_N to Ground				-	-	-	-	60	-	pF	
Feedthrough	C_{IOS}			-	-	-	-	0.6	-	pF	
CONTROLS											
Propagation Delay Time: High Impedance to High Level or Low Level Strobe to Output, CD22101	t_{PZH}, t_{PZL}	6	$R_L = 1\text{k}\Omega, C_L = 50\text{pF}, t_R, t_F = 20\text{ns}$				5	-	500	1000	ns
							10	-	230	460	ns
							15	-	170	340	ns
Data-In to Output, CD22101	t_{PZH}, t_{PZL}	7	$R_L = 1\text{k}\Omega, C_L = 50\text{pF}, t_R, t_F = 20\text{ns}$				5	-	515	1000	ns
							10	-	220	440	ns
							15	-	170	340	ns
K_A to Output, CD22102	t_{PZH}, t_{PZL}	-	$R_L = 1\text{k}\Omega, C_L = 50\text{pF}, t_R, t_F = 20\text{ns}$				5	-	500	1000	ns
							10	-	215	430	ns
							15	-	160	320	ns
Address to Output CD22101, CD22102	t_{PZH}, t_{PZL}	8	$R_L = 1\text{k}\Omega, C_L = 50\text{pF}, t_R, t_F = 20\text{ns}$				5	-	480	960	ns
							10	-	225	450	ns
							15	-	155	300	ns

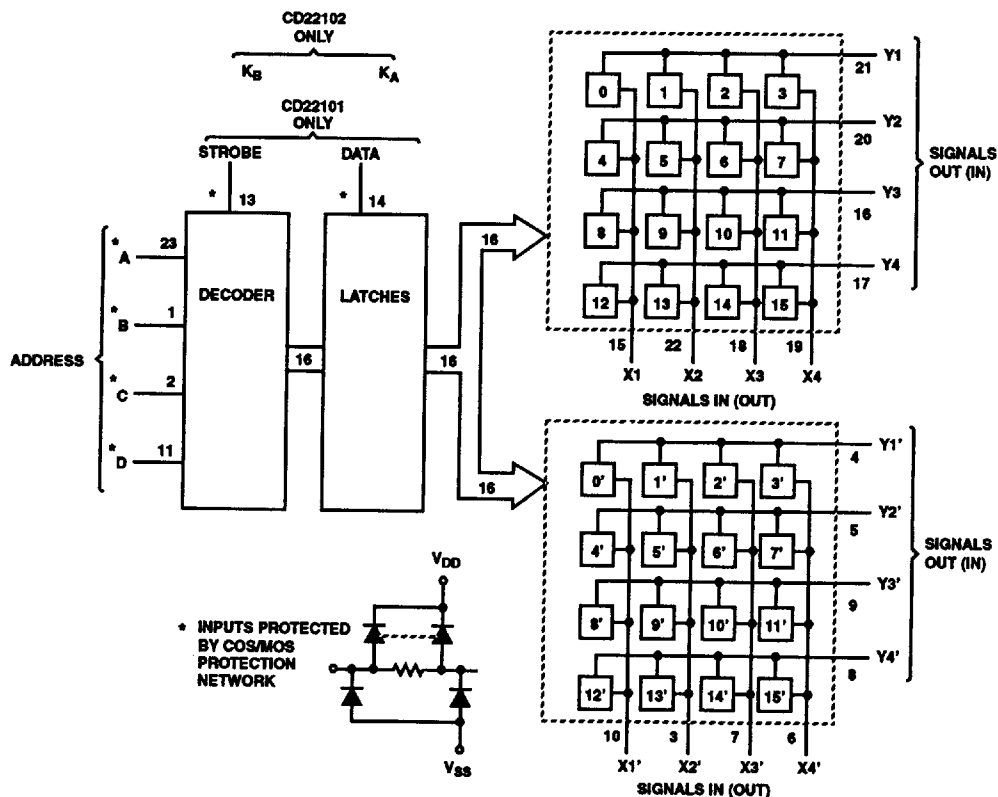
Specifications CD22101, CD22102

Dynamic Electrical Specifications $T_A = +25^\circ\text{C}$ (Continued)

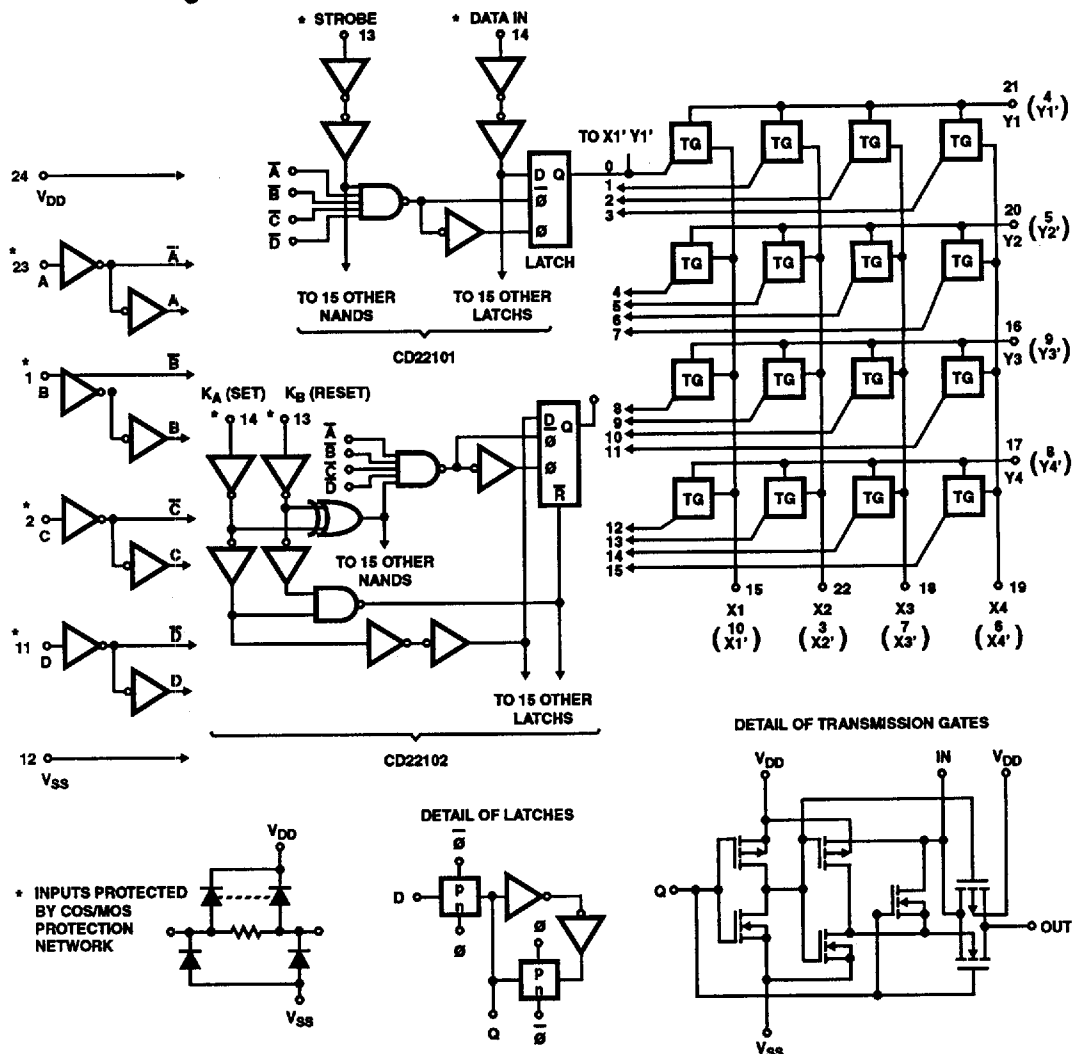
PARAMETERS	SYMBOL	TEST CONDITIONS					LIMITS			UNITS
		FIGURE	f_{IS} (kHz)	R_L (k Ω)	V_{IS} (V) (Note 3)	V_{DD} (V)	MIN	TYP	MAX	
CONTROLS (Continued)										
Propagation Delay Time: High Level or Low Level to High Impedance Strobe to Output, CD22101	t_{PHZ}, t_{PLZ}	6	$R_L = 1\text{k}\Omega, C_L = 50\text{pF},$ $t_R, t_F = 20\text{ns}$	5	-	450	900	ns		
				10	-	200	400	ns		
				15	-	135	270	ns		
K_B to Output, CD22102	t_{PHZ}, t_{PLZ}	-	$R_L = 1\text{k}\Omega, C_L = 50\text{pF},$ $t_R, t_F = 20\text{ns}$	5	-	450	900	ns		
				10	-	200	400	ns		
				15	-	130	260	ns		
Data-In to Output, CD22101	t_{PHZ}, t_{PLZ}	-	$R_L = 1\text{k}\Omega, C_L = 50\text{pF},$ $t_R, t_F = 20\text{ns}$	5	-	450	900	ns		
				10	-	165	330	ns		
				15	-	110	220	ns		
$K_A \bullet K_B$ to Output, CD22102	t_{PHZ}, t_{PLZ}	-	$R_L = 1\text{k}\Omega, C_L = 50\text{pF},$ $t_R, t_F = 20\text{ns}$	5	-	280	560	ns		
				10	-	130	260	ns		
				15	-	90	180	ns		
Address to Output CD22101, CD22102	t_{PHZ}, t_{PLZ}	8	$R_L = 1\text{k}\Omega, C_L = 50\text{pF},$ $t_R, t_F = 20\text{ns}$	5	-	425	850	ns		
				10	-	190	380	ns		
				15	-	130	260	ns		
Minimum Strobe Pulse Width, CD22101	t_W	6	$R_L = 1\text{k}\Omega, C_L = 50\text{pF},$ $t_R, t_F = 20\text{ns}$	5	-	260	500	ns		
				10	-	120	240	ns		
				15	-	80	160	ns		
Address to Strobe Setup or Hold Times, CD22101	t_{SU}, t_H	9	$R_L = 1\text{k}\Omega, C_L = 50\text{pF},$ $t_R, t_F = 20\text{ns}$	5	-	-160	0	ns		
				10	-	-70	0	ns		
				15	-	-50	0	ns		
Strobe to Data-In Hold Time, CD22101	t_{HHL}, t_{HLH}	10	$R_L = 1\text{k}\Omega, C_L = 50\text{pF},$ $t_R, t_F = 20\text{ns}$	5	-	200	400	ns		
				10	-	80	160	ns		
				15	-	60	120	ns		
Address to K_A and K_B Setup or Hold Times, CD22102	t_{SU}, t_H	-	$R_L = 1\text{k}\Omega, C_L = 50\text{pF},$ $t_R, t_F = 20\text{ns}$	5	-	-160	0	ns		
				10	-	-70	0	ns		
				15	-	-50	0	ns		
Minimum $K_A \bullet K_B$ Pulse Width, CD22102	t_W	-	$R_L = 1\text{k}\Omega, C_L = 50\text{pF},$ $t_R, t_F = 20\text{ns}$	5	-	375	750	ns		
				10	-	160	320	ns		
				15	-	110	220	ns		
Minimum K_A Pulse Width, CD22102	t_W	-	$R_L = 1\text{k}\Omega, C_L = 50\text{pF},$ $t_R, t_F = 20\text{ns}$	5	-	425	850	ns		
				10	-	175	350	ns		
				15	-	120	240	ns		
Minimum K_B Pulse Width, CD22102	t_W	-	$R_L = 1\text{k}\Omega, C_L = 50\text{pF},$ $t_R, t_F = 20\text{ns}$	5	-	200	400	ns		
				10	-	90	180	ns		
				15	-	70	140	ns		

- NOTE:
3. Peak-to-peak voltage symmetrical about $\frac{V_{DD}}{2}$, unless otherwise specified.
4. RMS

Functional Block Diagram



Schematic Diagram



DECODER TRUTH TABLE

ADDRESS				SELECT	ADDRESS				SELECT
A	B	C	D		A	B	C	D	
0	0	0	0	X1Y1 and X1'Y1'	0	0	0	1	X1Y3 and X1'Y3'
1	0	0	0	X2Y1 and X2'Y1'	1	0	0	1	X2Y3 and X2'Y3'
0	1	0	0	X3Y1 and X3'Y1'	0	1	0	1	X3Y3 and X3'Y3'
1	1	0	0	X4Y1 and X4'Y1'	1	1	0	1	X4Y3 and X4'Y3'
0	0	1	0	X1Y2 and X1'Y2'	0	0	1	1	X1Y4 and X1'Y4'
1	0	1	0	X2Y2 and X2'Y2'	1	0	1	1	X2Y4 and X2'Y4'
0	1	1	0	X3Y2 and X3'Y2'	0	1	1	1	X3Y4 and X3'Y4'
1	1	1	0	X4Y2 and X4'Y2'	1	1	1	1	X4Y4 and X4'Y4'

CONTROL TRUTH TABLE FOR CD22101

FUNCTION	ADDRESS				STROBE	DATA	SELECT
	A	B	C	D			
Switch On	1	1	1	1	1	1	15 (X4Y4) and 15' (X4'Y4')
Switch Off	1	1	1	1	1	0	15 (X4Y4) and 15' (X4'Y4')
No Change	X	X	X	X	0	X	X X X X

1 = High Level

0 = Low Level

X = Don't Care

CONTROL TRUTH TABLE FOR CD22102

FUNCTION	ADDRESS				K _A	K _B	SELECT
	A	B	C	D			
Switch On	1	1	1	1	1	0	15 (X4Y4) and 15' (X4'Y4')
Switch Off	1	1	1	1	0	1	15 (X4Y4) and 15' (X4'Y4')
All Switches Off (Note 5)	X	X	X	X	1	1	All
No Change	X	X	X	X	0	0	X X X X

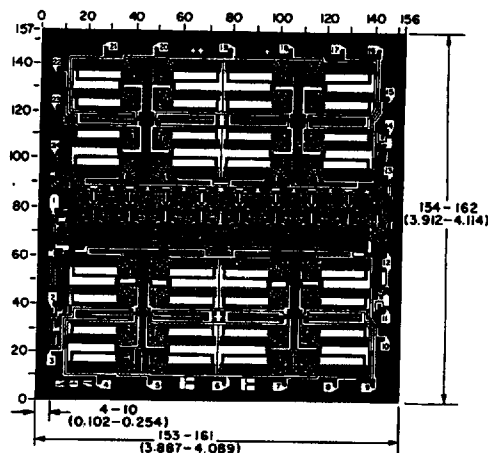
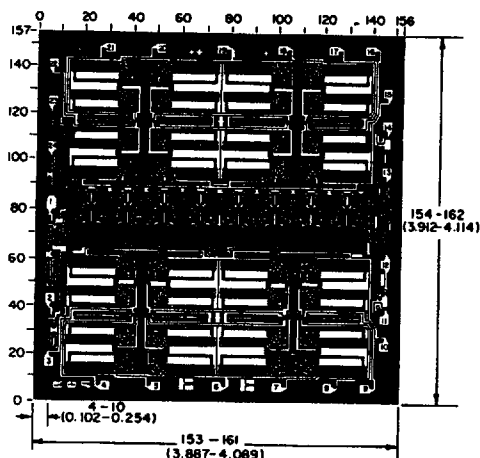
1 = High Level

0 = Low Level

X = Don't Care

NOTE:

5. In the event that K_A and K_B are changed from levels 1, 1 to 0, 0 K_B should not be allowed to go to 0 before K_A, otherwise a switch which was off will inadvertently be turned on.

Metallization Mask Layout

Dimensions in parenthesis are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

Test Circuits and Waveforms

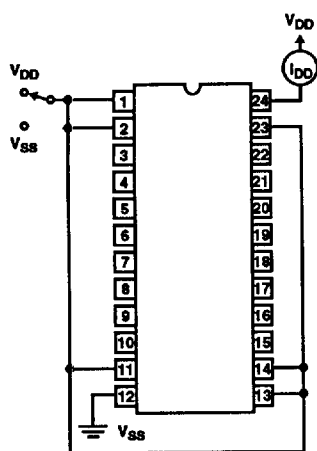
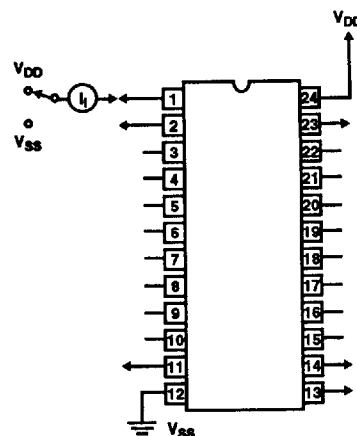
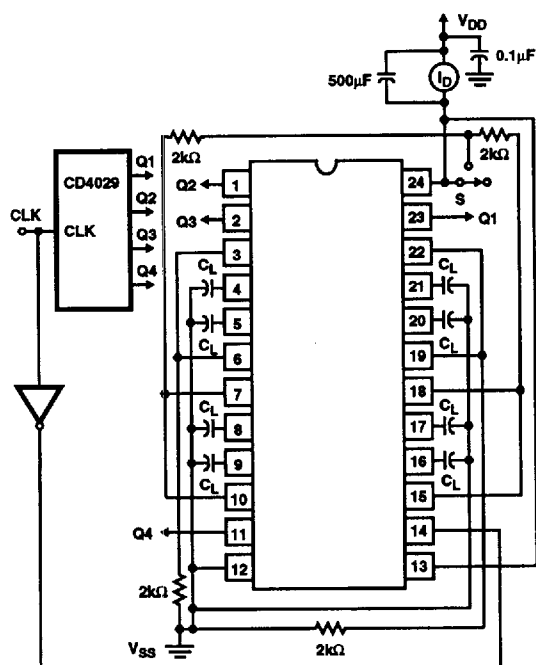


FIGURE 1. QUIESCENT CURRENT TEST CIRCUIT



NOTE:
MEASURE INPUTS SEQUENTIALLY TO BOTH V_{DD} AND V_{SS}
CONNECT ALL UNUSED INPUTS TO EITHER V_{DD} OR V_{SS}

FIGURE 2. INPUT CURRENT TEST CIRCUIT



NOTE:
CLOSE SWITCH S AFTER APPLYING V_{DD}

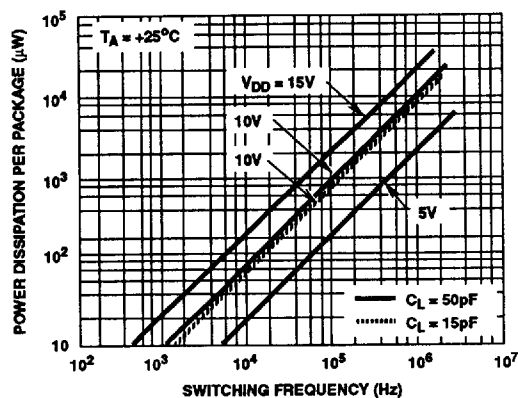
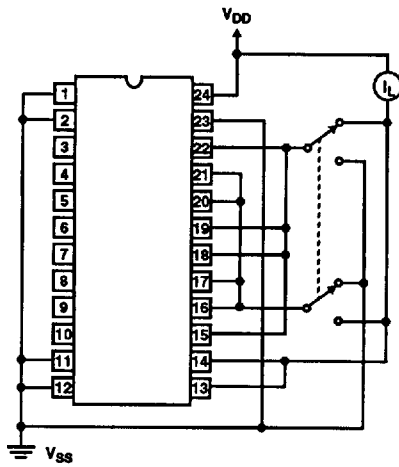
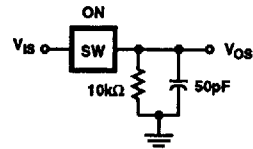
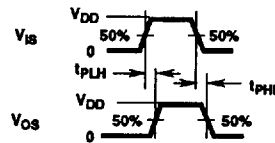
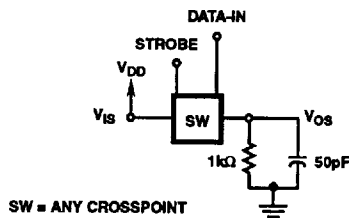


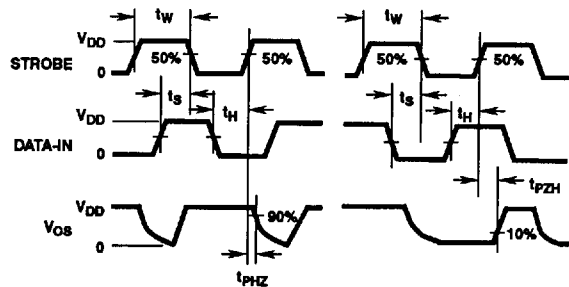
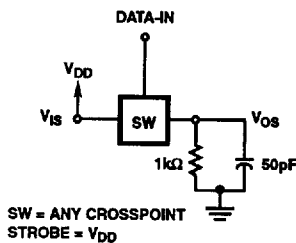
FIGURE 3. DYNAMIC POWER DISSIPATION TEST CIRCUIT FOR CD22101 AND TYPICAL DYNAMIC POWER DISSIPATION AS A FUNCTION OF SWITCHING FREQUENCY

Test Circuits and Waveforms (Continued)

FIGURE 4. OFF SWITCH INPUT OR OUTPUT LEAKAGE CURRENT TEST CIRCUIT (16 OF 32 SWITCHES)


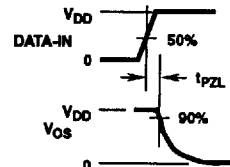
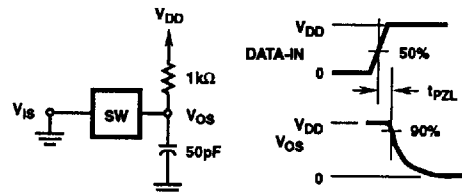
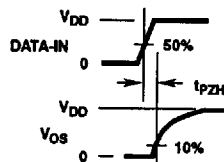
SW = ANY CROSSPOINT
STROBE = DATA - IN = V_{DD}

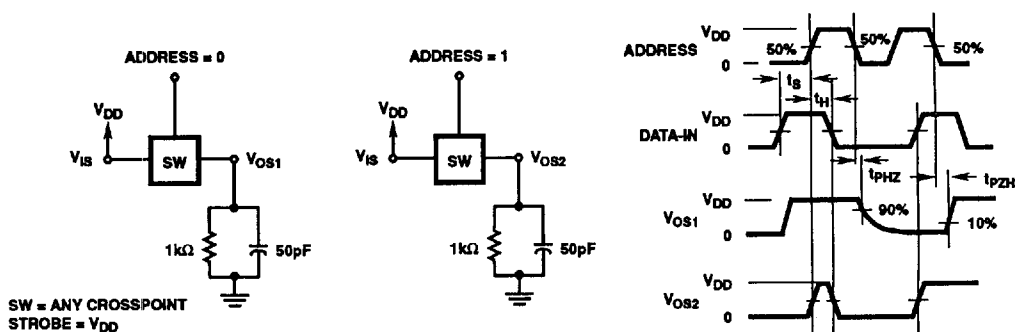
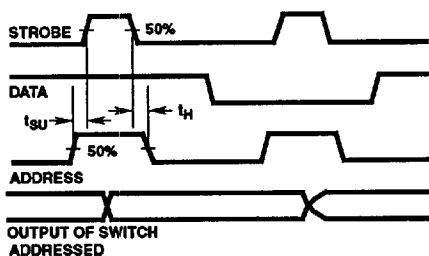

FIGURE 5. PROPAGATION DELAY TIME TEST CIRCUIT AND WAVEFORMS (SIGNAL INPUT TO SIGNAL OUTPUT, SWITCH ON)


SW = ANY CROSSPOINT

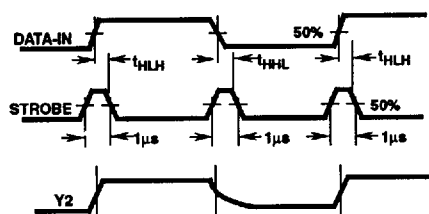

FIGURE 6. PROPAGATION DELAY TIME TEST CIRCUIT AND WAVEFORMS (STROBE TO SIGNAL OUTPUT, SWITCH TURN-ON OR TURN-OFF)


SW = ANY CROSSPOINT
STROBE = V_{DD}

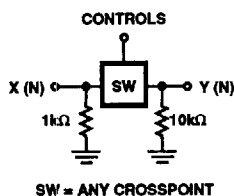

FIGURE 7. PROPAGATION DELAY TIME TEST CIRCUIT AND WAVEFORMS (DATA-IN TO SIGNAL OUTPUT, SWITCH TURN-ON TO HIGH OR LOW LEVEL)

Test Circuits and Waveforms (Continued)**FIGURE 8. PROPAGATION DELAY TIME TEST CIRCUIT AND WAVEFORMS**
(ADDRESS TO SIGNAL OUTPUT, SWITCH TURN-ON OR TURN-OFF)

NOTE:
IF SETUP AND HOLD TIMES PROVIDED ARE TOO SHORT,
AN UNADDRESSED SWITCH MAY BE TURNED ON OR OFF
SIMULTANEOUSLY WITH THE ADDRESSED SWITCH

FIGURE 9. ADDRESS TO STROBE SETUP AND HOLD TIMES

NOTE:
SET ALL SWITCHES TO OFF INITIALLY APPLY V_{DD}
TO ALL X INPUTS AND RETURN ALL Y OUTPUTS TO
 V_{SS} THROUGH $1k\Omega$ ADDRESS X1Y2 (ABCD) WITH $f_{IN} = 10kHz$

FIGURE 10. STROBE TO DATA-IN HOLD TIME t_H , FOR CD22101**FIGURE 11. TEST CIRCUIT AND WAVEFORMS FOR CROSSTALK (CONTROL INPUT TO SIGNAL OUTPUT)**

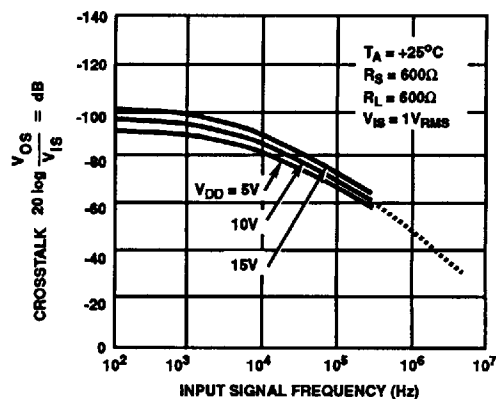
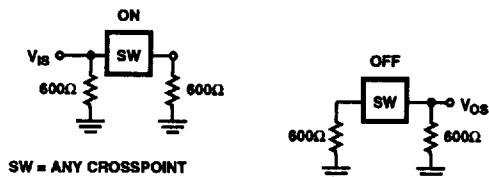
Test Circuits and Waveforms (Continued)

FIGURE 12. TEST CIRCUIT AND TYPICAL CROSSTALK AS A FUNCTION OF FREQUENCY BETWEEN SWITCH CIRCUITS IN THE SAME PACKAGE

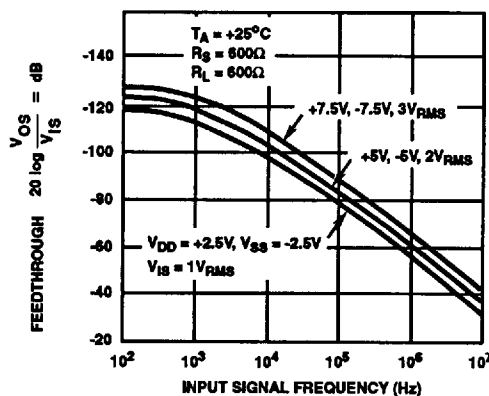
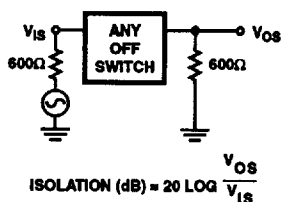


FIGURE 13. TEST CIRCUIT AND TYPICAL FEEDTHROUGH AS A FUNCTION OF FREQUENCY (ANY OFF SWITCH)

Typical Performance Curves

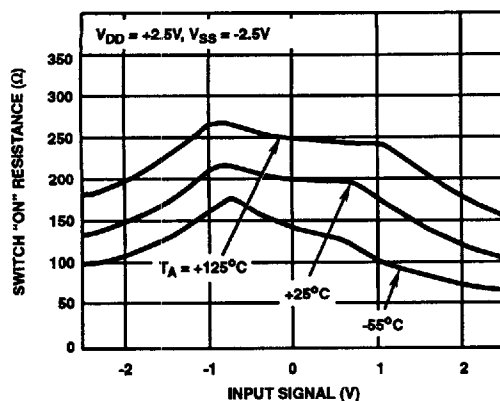


FIGURE 14. TYPICAL ON RESISTANCE AS A FUNCTION OF INPUT SIGNAL VOLTAGE AT $V_{DD} = -V_{SS} = 2.5V$

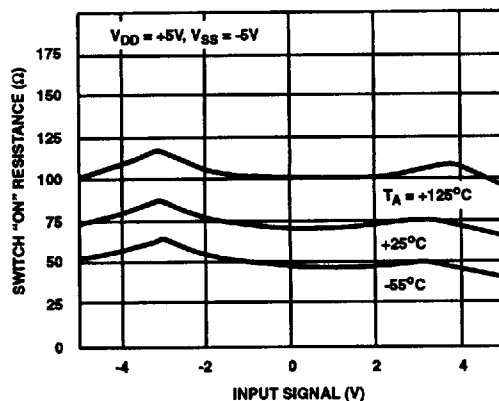


FIGURE 15. TYPICAL ON RESISTANCE AS A FUNCTION OF INPUT SIGNAL VOLTAGE AT $V_{DD} = -V_{SS} = 5V$

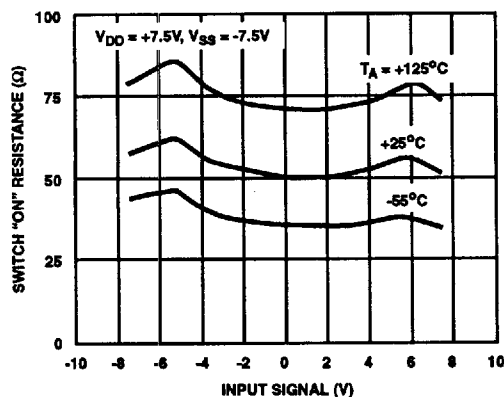


FIGURE 16. TYPICAL ON RESISTANCE AS A FUNCTION OF INPUT SIGNAL VOLTAGE AT $V_{DD} = -V_{SS} = 7.5V$

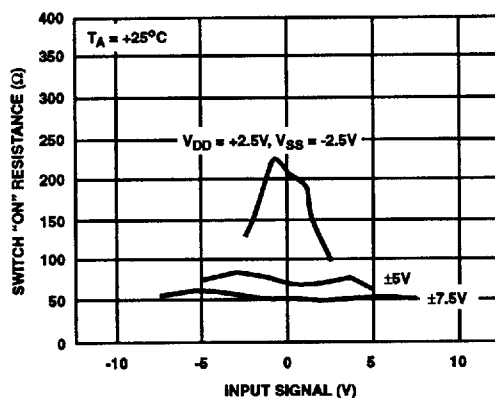


FIGURE 17. TYPICAL ON RESISTANCE AS A FUNCTION OF INPUT SIGNAL VOLTAGE AT $T_A = +25^\circ C$

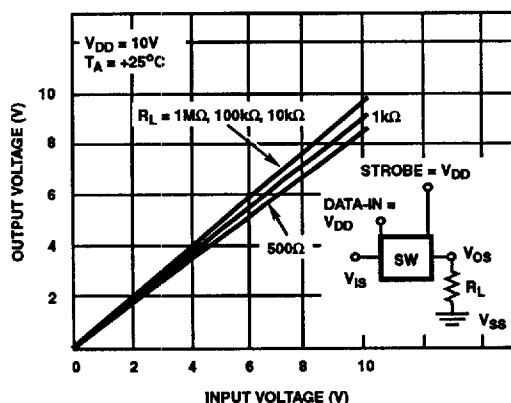


FIGURE 18. TYPICAL SWITCH ON TRANSFER CHARACTERISTICS (1 OF 16 SWITCHES)

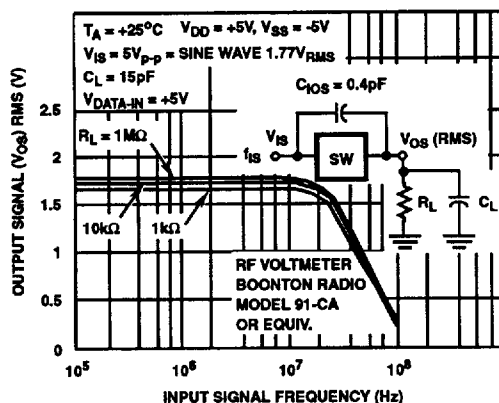


FIGURE 19. TYPICAL SWITCH ON FREQUENCY RESPONSE CHARACTERISTICS